

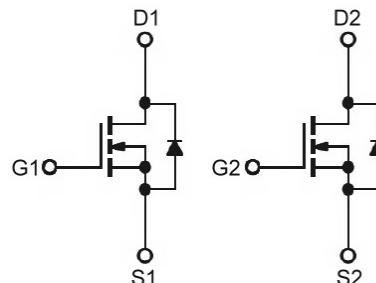
MSH40N095D

Dual N-Channel 40-V (D-S) MOSFET

Description

The device is using trench DMOS technology. This advanced technology has been especially tailored to minimize $R_{DS(ON)}$, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficiency fast switching applications.

Graphic Symbol

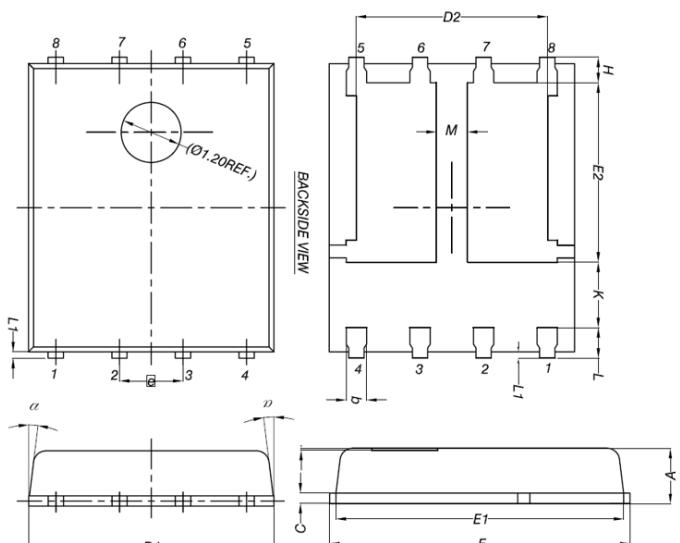


Features

- $R_{DS(ON)} = 9.5\text{m}\Omega$ @ $V_{GS} = 10\text{V}$
- Fast switching
- Improve dv/dt Capability
- 100% EAS Guaranteed
- Green Device Available

Typical Applications

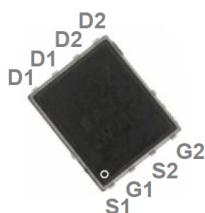
- Notebook
- Load Switch
- Hand-held Device



Package type : PDFN 5X6 Dual

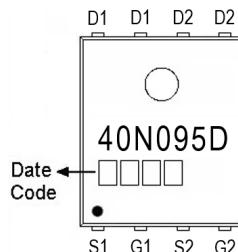
Packing & Order Information

3,000/Reel



| REF. | Millimeter | | | REF. | Millimeter | | |
|------|------------|------|------|------|------------|------|------|
| | Min. | Nom. | Max. | | Min. | Nom. | Max. |
| A | 0.90 | 1.10 | 1.10 | E2 | 3.38 | 3.58 | 3.78 |
| b | 0.33 | 0.41 | 0.51 | H | 0.41 | 0.51 | 0.61 |
| C | 0.20 | 0.25 | 0.30 | K | 1.10 | - | 6.20 |
| D1 | 4.80 | 4.90 | 5.00 | L | 0.51 | 0.61 | 0.71 |
| D2 | 3.61 | 3.81 | 3.96 | L1 | 0.06 | 0.13 | 0.20 |
| E | 5.90 | 6.00 | 6.10 | M | 0.50 | - | - |
| E1 | 5.70 | 5.75 | 5.80 | a | 0°C | - | 12°C |
| e | 1.27 BSC | | | | | | |

Marking



RoHS Compliant

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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

| Absolute Maximum Ratings (T _c =25°C unless otherwise noted) | | | |
|--|---|----------|------|
| Symbol | Parameter | Value | Unit |
| V _{DS} | Drain-Source Voltage | 40 | V |
| V _{GS} | Gate-Source Voltage | ±20 | V |
| I _D | Continuous Drain Current @ T _c =25°C | 21 | A |
| | Continuous Drain Current @ T _c =70°C | 12 | A |
| I _{DM} | Pulsed Drain Current ² | 60 | A |
| I _{AS} | Single Pulse Avalanche Current, L =0.1mH ³ | 20 | A |
| E _{AS} | Single Pulse Avalanche Energy, L =0.1mH ³ | 20 | mJ |
| P _D | Power Dissipation (T _c =25°C) | 8 | W |
| T _j , T _{stg} | Operating Junction and Storage Temperature | -55~+150 | °C |

Thermal Resistance Ratings

| Symbol | Parameter | Value | Unit |
|------------------|--|-------|------|
| R _{θJA} | Maximum Junction-to-Ambient ¹ | 65 | °C/W |
| R _{θJC} | Maximum Junction-to-Case | 5 | °C/W |

Electrical Characteristics (T_J=25°C unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Units |
|----------------------|--|---|------|------|------|-------|
| V _{GS (th)} | Gate Threshold Voltage | V _{DS} =V _{GS} , I _D =250μA | 1.2 | - | 2.2 | V |
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =250μA | 40 | - | - | V |
| I _{GSS} | Gate-Source Leakage Current | V _{DS} =0V, V _{GS} =±20V | - | - | ±100 | nA |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =30V, V _{GS} =0V, T _J =25°C | - | - | 1 | μA |
| | | V _{DS} =30V, V _{GS} =0V, T _J =55°C | | | 5 | |
| R _{DS (on)} | Static Drain-Source On-Resistance ² | V _{GS} =10V, I _D =20A | - | 7.8 | 9.5 | mΩ |
| | | V _{GS} =4.5V, I _D =15A | - | 12 | 17 | |
| EAS | Single Pulse Avalanche Energy ⁵ | V _{DD} =25V, L =0.1mH, I _{AS} =20A | 5 | - | - | mJ |
| V _{SD} | Diode Forward Voltage ² | I _S =1A, V _{GS} =0V, T _J =25°C | - | - | 1 | V |
| I _S | Continuous Source Current ^{1,6} | V _G =V _D =0V, Force Current | - | - | 20 | A |
| I _{SM} | Pulsed Source Current ^{2,6} | | - | - | 40 | |

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| Dynamic | | | | | | |
|--------------|---------------------------------|---|------|------|------|----------|
| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Units |
| Q_g | Total Gate Charge ² | $V_{DS} = 20V$ $I_D = 12A$ $V_{GS} = 10V$ | -- | 5.8 | -- | nC |
| Q_{gs} | Gate-Source Charge | | -- | 3 | -- | |
| Q_{gd} | Gate-Drain Charge | | -- | 1.2 | -- | |
| $t_{d(on)}$ | Turn-On Delay Time ² | $V_{DS} = 15V$ $I_D = 1A$ $V_{GS} = 10V$ $R_G = 3.3\Omega$ | -- | 14.3 | -- | ns |
| t_r | Rise Time | | -- | 5.6 | -- | |
| $t_{d(off)}$ | Turn-Off Delay Time | | -- | 20 | -- | |
| t_f | Fall Time | | -- | 11 | -- | |
| C_{iss} | Input Capacitance | $V_{DS} = 15V$ $V_{GS} = 0V$ $f = 1.0MHz$ | -- | 690 | -- | pF |
| C_{oss} | Output Capacitance | | -- | 193 | -- | |
| C_{rss} | Reverse Transfer Capacitance | | -- | 38 | -- | |
| R_g | Gate Resistance | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$ | | 1.7 | | Ω |

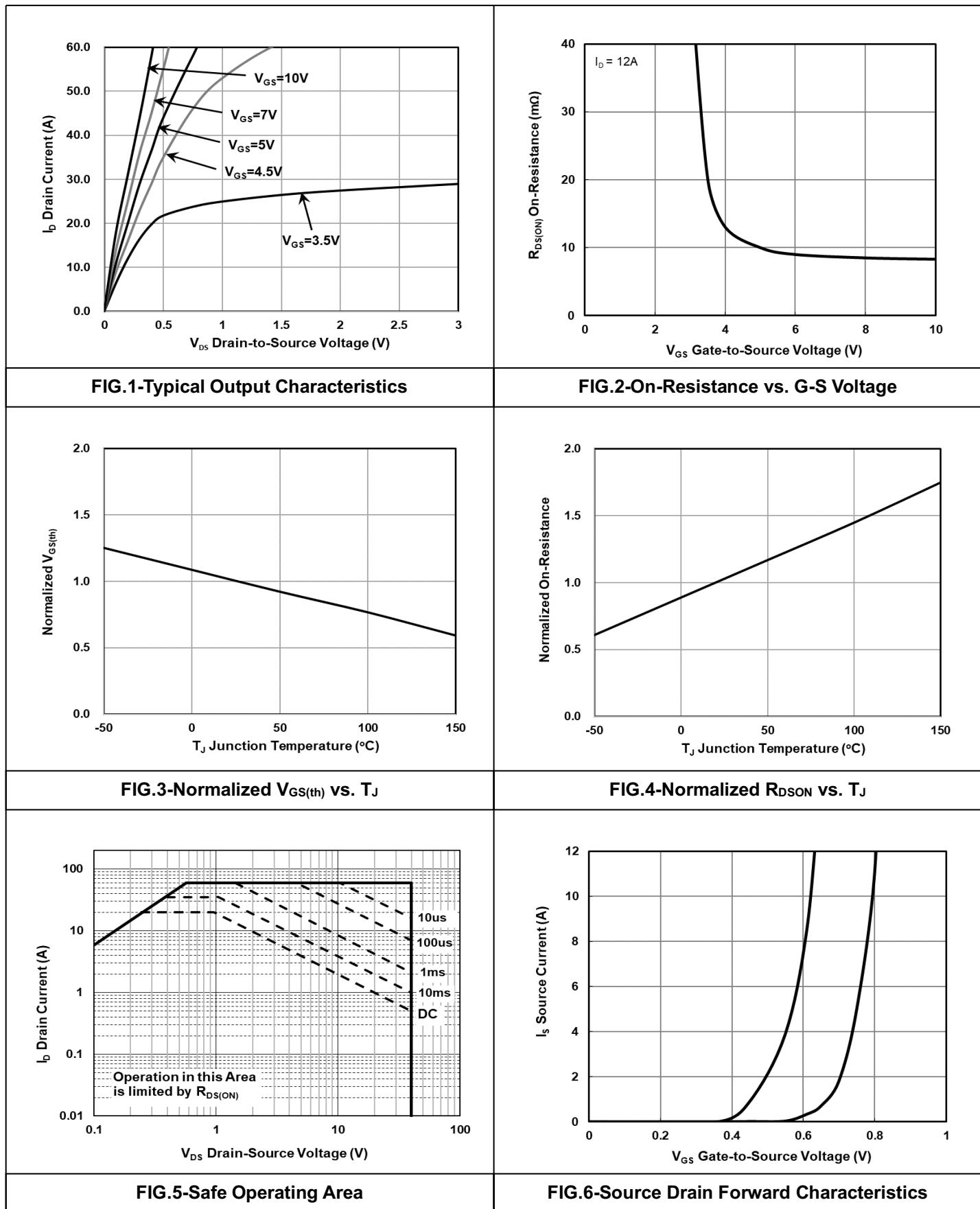
Notes

1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
2. The data tested by pulsed, pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
3. The EAS data shows maximum rating. The test condition is $V_{DD} = 25V$, $V_{GS} = 10V$, $L = 0.1mH$, $I_{AS} = 20A$.
4. The power dissipation is limited by 150°C junction temperature.
5. The Min. value is 100% EAS tested guarantee.
6. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.

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- **Typical Electrical Characteristics**



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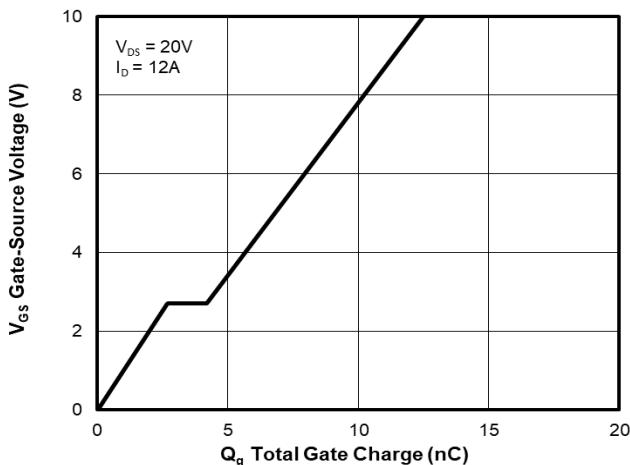


FIG.7-Gate Charge Characteristics

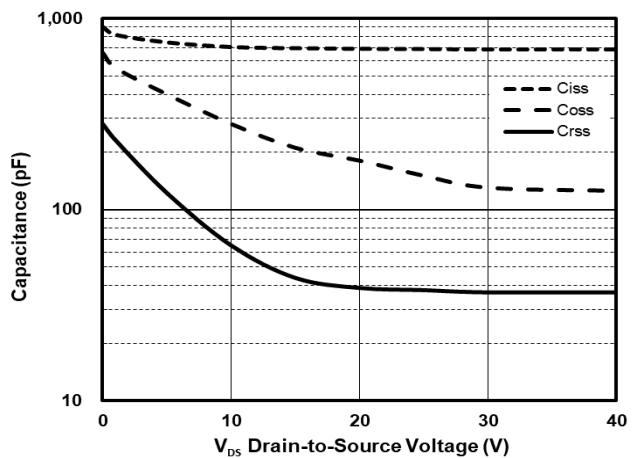


FIG.8-Capacitance Characteristics

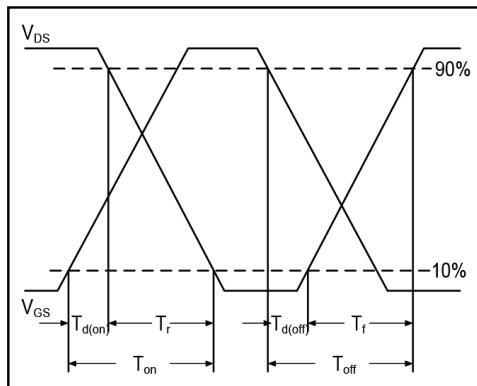


FIG.9-Switching Time Waveform

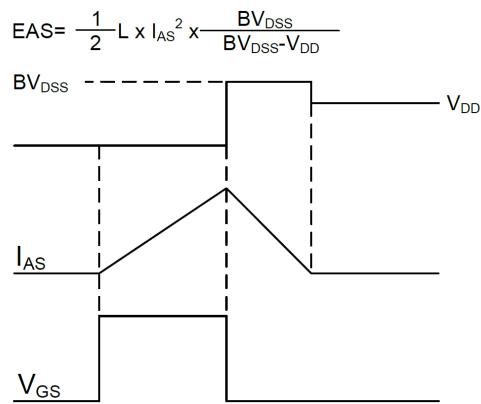


FIG.10-Unclamped Inductive Switching Waveform

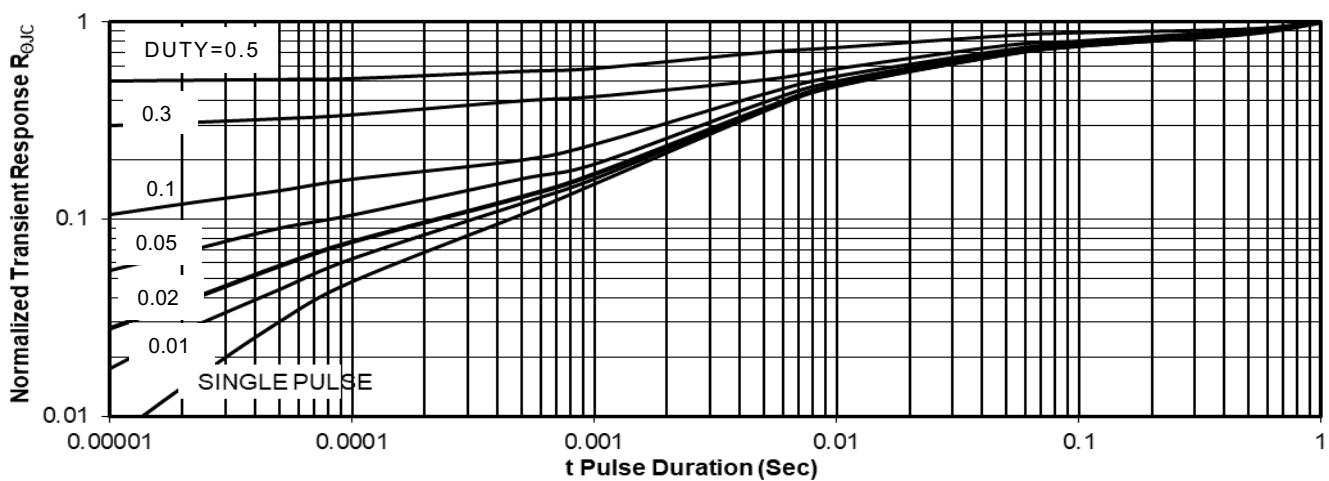


FIG.11-Normalized Maximum Transient Thermal Impedance

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